

## Challenges and progress in design of Electical IC's for Analog Drive Optics

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# Introduction to InSiGa



Company started in July 2016 Focus is on high speed optical communication market -10Gbs to 800Gbs

Fabless business model Differentiation-Low power, small size IC's for 10-800Gbs market



# Market Focus

5G Mid haul 5G Back haul 5G Front haul 200G-800G Coherent 100G Datacenter 200G Datacenter 400G Datacenter 800G Datacenter 10G PON (OLT) 50G PON



- Accelerated adoption of higher bandwidth modules
- Multi level Modulation schemes (PAM4, QAM) in mass deployment already
- DSP driven modules primarily for PAM4 modulation
- High cost pressures
- Bandwidth doubling almost every 2-3 years
- Silicon Photonics becoming prevalent for high speed modules



- DML (Directly Modulated Lasers)
- EML (Electrically Modulated Lasers)
- Thin Film Lithium Niobate based MZ
- Silicon Photonics based MZ



# Comparison of eye @ 53Gbauds

#### DML@53Gbaud/s

#### EML@53Gbaud/s

#### Si Photonics@53Gbaud/s



Outer ER=4dB TDECQ=2.2dB







# **Optical Technology Choices – Transmitter**

#### For 53Gbaud/s PAM4 (100Gbs/lane)

Parameter	DML	EML	Si Ph	TFLN
Performance	3	2	1	-
Cost	1	3	2	-
Power	1	2	2	-
Scalability	2	2	1	-

Ranking – 1 is best, 3 is worst



# Silicon Photonics – Challenges

- Power Dissipation
  - □Vpi ( high drive)
  - **High power lasers**
- Optical Coupling
- Controls- Heater, Bias, CW laser



# Silicon Modulator Design- Key Parameters

### Key parameters for Si MZ Modulator design

- □Vpi ↓
- □Bandwidth ↑
- $\Box$ Optical Loss  $\downarrow$
- $\Box$ Length of Modulator (size)  $\downarrow$
- $\Box$ Impedance of Modulator  $\uparrow$



#### Key parameters for Si Photonics Modulator Driver design

- □Output Swing ↑
- □Bandwidth ↑
- □Size↓
- □Gain ↑
- $\Box$ Linearity (THD  $\downarrow$  )
- $\Box$ Impedance of Driver  $\uparrow$
- $\Box$  Power Dissipation  $\downarrow$



#### InSiGa 400Gbs Driver- ISG-D5640 (Technology – SiGe)

- Output Swing- 3.5Vpp
- Bandwidth > 40GHz
- Die Size 1.7x3.7mm
- Gain 17dB
- THD < 3%
- Driver Impedance- Very high
- Power Dissipation/ch- 260mW



- $\Box$  Impedance of Driver  $\uparrow$
- lacksquare Power Dissipation  $\checkmark$



## Silicon based Receiver - Key Parameters

#### Key parameters for Receiver design

- $\Box$  Bandwidth  $\uparrow$
- $\Box$ Optical Loss  $\checkmark$
- $\Box$  Dark Current  $\checkmark$
- □ PD Responsivity↑
- $\square$  PD Parasitic Capacitance  $\checkmark$



## Transimpedance Amplifier(TIA) - Key parameters

Key parameters for TIA design

□ Noise↓
□ Bandwidth ↑
□ Size↓
□ Gain ↑
□ Linearity (THD ↓)
□ Power Dissipation ↓



## InSiGa 400Gbs TIA- ISG-T5743 (Technology – SiGe)

- Input Noise- 2.2uA
- Bandwidth > 30GHz
- Die Size 1.3x2.35mm
- Gain 4.5kohm
- THD < 3%
- Power Dissipation/ch-160mW

- 🗖 Noise 🗸
- $\Box$  Bandwidth  $\uparrow$
- □ Size↓
- 🗖 Gain ↑

□ Linearity (THD ↓)

 $\Box$  Power Dissipation  $\downarrow$ 



VDD=3.3V, IDD=39mA, GC=2.5V, PD Cap=80fF, <u>Rpd</u>=10ohm, <u>Lbw</u>=0.5nH





## **ANALOG DRIVE OPTICS (ADO)**





What are Analog Drive Modules (ADM)?

## **Analog Drive Modules - Modules without DSP**









#### No gearbox requirement

• Input Signal rate and modulation is same as optical output



Analog Drive Modules - Modules without DSP



## **Analog Drive Modules - Modules without DSP**

#### Advantages

- Low Cost
- Low Power Dissipation
- Higher channel/bandwidth density
- Low Latency



## Analog Drive Modules - Modules without DSP

#### Challenges

- Overcoming channel Loss on host/module
- Connector Mismatch issues (No resonance in band due to connector and module interface)
- Phase/Group Delay Compensation



## What are challenges for Modulator Driver for ADM?

#### **Challenges for Modulator Driver Design**

- Equalization capability to compensate for losses
- Good Input return loss to minimize reflection issues
- Good Phase response (Group delay)
- Good linearity



m7

15

10

20

freq, GHz

25

30

0

-2-

-4-

-6--8-

-10-

-12-

-14-

-16

Relative Gain (dB)

freq=26.50GHz dB(S(1,2))+42-.4=-1.554

m7

35

40

45

## Measured Driver + PIC Performance on EVB

45

40

35

30

25

15

10

5

20

freq, GHz

**Test Setup** 

Si PIC

FA

Lowest Equalization from InSiGa Driver- ISG-D5640

-35-



## Measured Driver + PIC Performance on EVB



Si PIC

Maximum Equalization from InSiGa Driver- ISG-D5640



## Test Setup with PCB loss



Loss of PCB – 14cm trace



#### Measured Eye at 26.5Gbaud/s

#### TDECQ=2.09dB



#### TDECQ=4.5dB



#### Without Equalization from Driver

#### With Equalization from Driver



## Measured BER with Loss



#### 14cm of PCB loss at TX input 14cm of PCB loss at RX Output

#### RX side uses InSiGa's TIA ISG-T5713 inside a TO







### Measured Eye at 53Gbaud/s

#### TDECQ=1.8dB



#### With No loss at TX input

#### TDECQ=2.7dB



#### With Equalization after loss at TX input



# AOC – Eg. 400G (50Gx8)

#### Advantages

- The Equalization from TX can be optimized to get best BER- can compensate for RX side by over-equalization on TX
- High number of channels bring out true value of Silicon PIC's
- Length of Cable can easily reach >100m
- SM Fiber array cost cheaper than MM fiber array
- Power Dissipation lower than DSP/CDR driven modules

#### Measured BER data shows high probability of this solution being able to meet system requirements



## ADM - applications

# AOC – 400G (100Gx4)

#### Advantages

- The Equalization from TX can be optimized to get best BER- can compensate for RX side by over-equalization on TX
- Length of Cable can easily reach >100m
- SM Fiber array cost cheaper than MM fiber array
- Power Dissipation lower than DSP/CDR driven modules

#### FFE capability on RX side for 100G IO (switch and NIC) will be important factor in determining performance



### ADM – applications

## High Performance Computing (HPC) – Low Latency requirements

#### Advantages

- The solution can be based on high speed NRZ modulation without FEC (50Gbs NRZ) to achieve high bandwidth - Eg. 50Gbs x 8 for 400G requirements
- Lowest latency

#### **50G NRZ**



Error free operation from -9dBm to 2dBm OMA



## ADM - applications

## 400G DR4

## Challenges

- TX and RX need to be independently optimized
- Higher Loss budget compared to AOC
- Gain of TIA needs to be higher
- Pre-emphasis capability from TIA?

Need testing with 100G I/O on Switch/NIC to determine exact TX and RX requirements



## Analog Drive Optical Engines

#### **CPO – Co-Packaged Optics**

### Challenges

- Density (Area)
- Power Dissipation (Heat Management)
- Packaging (2.5D vs 3D)
- Cost



## **CPO – Co-Packaged Optics**

## **Electrical IC direction**

- Density (Area)
  - **D** Equalization capability
  - □ 8 channels/die (pitch 375um)
  - Integrating Si PIC controls like CW laser bias control, heater control, MPD monitoring etc, with Driver IC
- Power Dissipation
  - □ (Removal of DSP, Low Power Driver- 260mW/ch)
- Packaging
  - □ Tight Pitch Cu Pillars for Flip-chip assembly



#### Advantages of Si PIC's

- Best linearity (DML, VCSEL have asymmetric rise/fall, EML single ended drive)
- High level of integration no. of channels, MPD etc.
- Bandwidth roll-off very linear- easier to equalize
- Temperature of Operation
- Cost



# Thank you!



# Questions?



